## NSN 5961-01-261-5289

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-261-5289 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case and electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source and 3.5 peak-point voltage and 7.0 peak-point voltage **Current Rating Per Characteristic:** 10.00 nanoamperes forward gate current with all other terminals short-circuited to source, insulated-gate **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No